TGBR20L45 Advance DIODE

TRENCH MOS SCHOTTKY BARRIER RECTIFIER

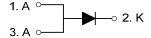
■ DESCRIPTION

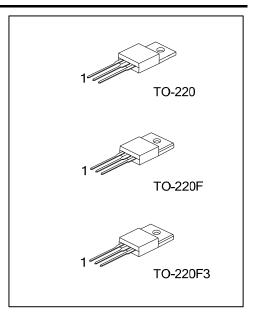
The UTC **TGBR20L45** is a trench mos schottky barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

■ FEATURES

- * Low forward voltage drop
- * High switching speed

■ SYMBOL

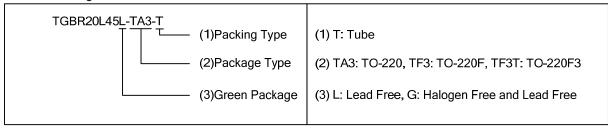




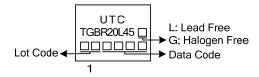
■ ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
TGBR20L45L-TA3-T	TGBR20L45G-TA3-T	TO-220	Α	K	Α	Tube	
TGBR20L45L-TF3-T	TGBR20L45G-TF3-T	TO-220F	Α	K	Α	Tube	
TGBR20L45L-TF3T-T	TGBR20L45G-TF3T-T	TO-220F3	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode K: Cathode



MARKING



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■ **ABSOLUTE MAXIMUM RATINGS**(T_A=25°C, unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	V_{RM}	45	V
WorkingPeak Reverse Voltage	V_{RWM}	45	V
Peak Repetitive Reverse Voltage	V_{RRM}	45	V
Average Rectified Output Current T _C =140°C	lo	20	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single	I _{FSM}	250	Α
Half Sine-Wave Superimposed on Rated Load	·F3W	PSIVI 200	
Operating Junction Temperature	T_J	-65~+150	°C
Storage Temperature	T_{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient		θ_{JA}	62.5	°C/W	
Junction to Case	TO-220	0	2	°C/M	
	TO-220F/TO-220F3	θ _{JC}	3.31	°C/W	

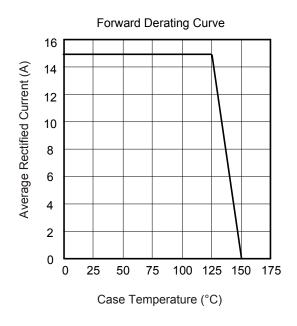
■ **ELECTRICAL CHARACTERISTICS**(T_A=25°C,unless otherwise specified.)

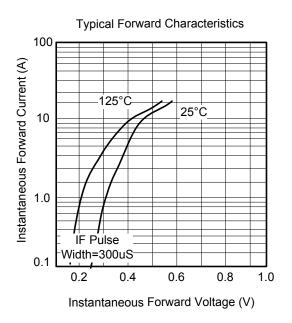
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.5mA	45			٧
Forward Voltage Drop	VEM	I _F =20A, T _J =25°C			0.59	V
		I _F =20A, T _J =125°C			0.54	V
Leakage Current (Note 1)	I PM	V _R =45V, T _J =25°C			300	μΑ
		V _R =45V, T _J =125°C			40	mΑ

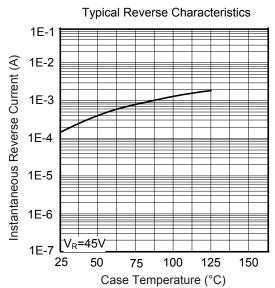
Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

■ TYPICAL CHARACTERISTICS







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